

T493A475K010BT6310

T493 HRA, Tantalum, MnO2 Tantalum, HRA, 4.7 uF, 10%, 10 VDC, SMD, MnO2, Molded, High Reliability, B (0.1%/1000 Hrs), 6 Ohms, 3216, 1.8 mm, 0.8 mm



General Information	
Series	T493 HRA
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, High Reliability
Features	High Reliability
RoHS	Yes
Termination	Tin
AEC-Q200	No
Typical Component Weight	58.97 mg
Notes	P and R dimensions represents the minimum solderable area of the termination surface entirely below cutout (if one is present).

Dimensions	
L	3.2mm +/-0.2mm
W	1.6mm +/-0.2mm
Н	1.6mm +/-0.2mm
Т	0.13mm REF
S	0.8mm +/-0.3mm
F	1.2mm +/-0.1mm
A	1.2mm MIN
В	0.4mm +/-0.15mm
E	1.3mm REF
G	1.1mm REF
Р	0.35mm MIN
R	0.4mm REF
X	0.1mm +/-0.1mm REF

Specifications	
Capacitance	4.7 uF
Tolerance	10%
Voltage DC	10 VDC (85C), 6.7 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	B (0.1%/1000 Hrs)
ESR	6 Ohms (100kHz 25C)
Ripple Current	112 mA (rms, 100kHz 25C)
Leakage Current	0.5 uA (5min 25°C)
Testing and Reliability	10 Cycles Surge Current Testing At -55C And +85C After Weibull

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	2000

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